

# 1000 V SenseFET Integrated Power Switch

## FSL4110LR

### Description

The FSL4110LR is an integrated pulse width modulation (PWM) controller and 1000 V avalanche rugged SenseFET specifically designed for high input voltage offline Switching Mode Power Supplies (SMPS) with minimal external components.  $V_{CC}$  can be supplied through integrated high-voltage power regulator without auxiliary bias winding.

The integrated PWM controller includes a fixed-frequency oscillator, Under-Voltage Lockout (UVLO), Leading-Edge Blanking (LEB), optimized gate driver, soft-start, temperature-compensated precise current sources for loop-compensation, and variable protection circuitry.

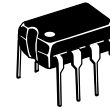
Compared with a discrete MOSFET and PWM controller solution, the FSL4110LR reduces total cost, component count, PCB size, and weight; while simultaneously increasing efficiency, productivity, and system reliability. This device provides a basic platform for cost-effective design of a flyback converter.

### Features

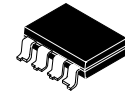
- Built-in Avalanche Rugged 1000 V SenseFET
- Precise Fixed Operating Frequency: 50 kHz
- $V_{CC}$  can be Supplied from either Bias-winding or Self-biasing
- Soft Burst-Mode Operation Minimizing Audible Noise
- Random Frequency Fluctuation for Low EMI
- Pulse-by-Pulse Current Limit
- Various Protection Functions: Overload Protection (OLP), Over-Voltage Protection (OVP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD) with Hysteresis. Under-Voltage Lockout (UVLO) and Line Over-Voltage Protection (LOVP) with Hysteresis.
- Built-in Internal Startup and Soft-Start Circuit
- Fixed 1.6 s Restart Time for Safe Auto-Restart Mode of All Protections
- These are Pb-Free Devices

### Applications

- SMPS for Electric Metering
- Auxiliary Power Supply for 3-Phase Input Industrial Systems

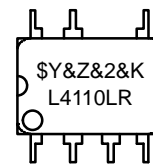


PDIP-7 (PDIP-8 LESS PIN 6)  
 (7-DIP)  
 CASE 626A

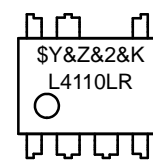


PDIP7 MINUS PIN 6 GW  
 (7-LSOP)  
 CASE 707AA

### MARKING DIAGRAM



FSL4110LRN



FSL4110LRLX

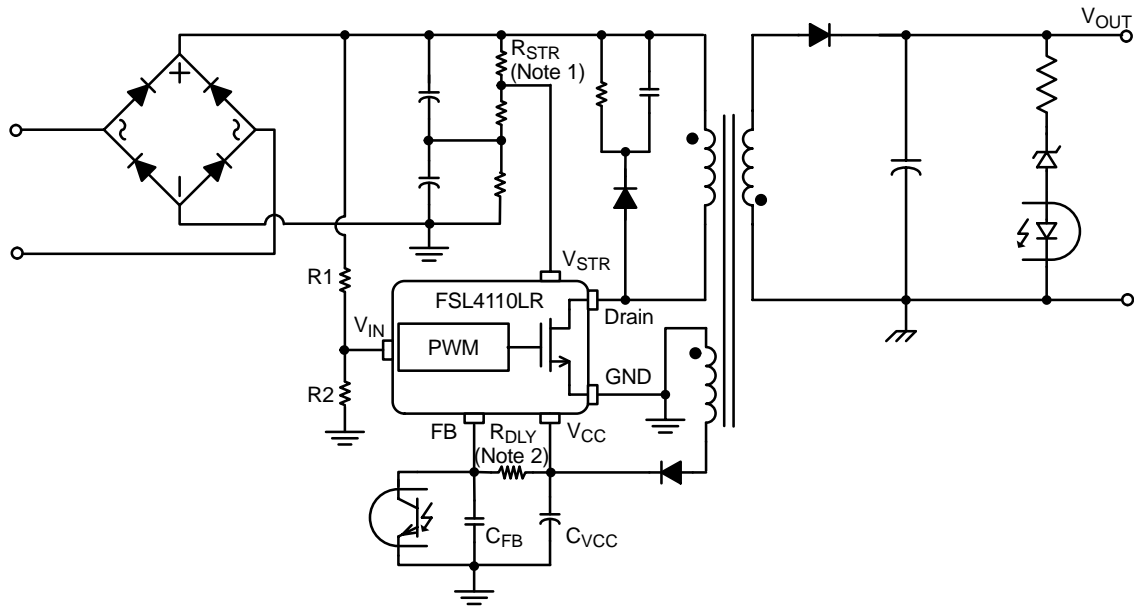
- \$Y = Logo
- &Z = Assembly Plant Code
- &2 = 2-Digit Date Code
- &K = 2-Digits Lot Run Traceability Code
- L4110LR = Specific Device Code

### ORDERING INFORMATION

See detailed ordering and shipping information on page 13 of this data sheet.

# FSL4110LR

## TYPICAL APPLICATION CIRCUIT



### NOTES:

1.  $R_{STR}$ : See the functional description [Startup and High-Voltage Regulator](#).
2.  $R_{DLY}$ : See the functional description [Overload Protection \(OLP\)](#).

Figure 1. Typical Application Circuit

## INTERNAL BLOCK DIAGRAM

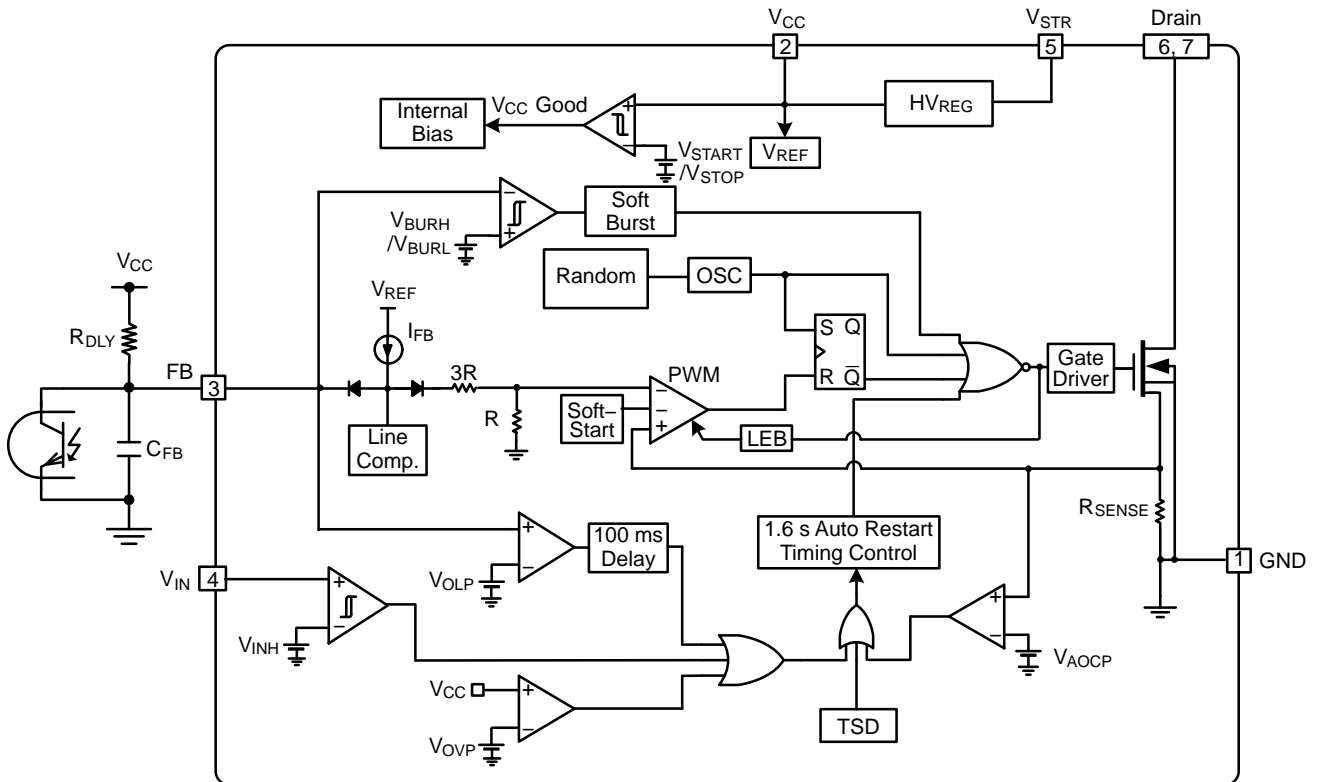


Figure 2. Internal Block Diagram

# FSL4110LR

## PIN CONFIGURATION

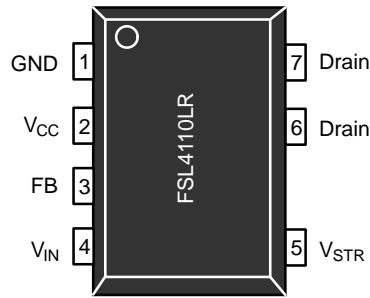


Figure 3. Pin Configuration (Top View)

## PIN DEFINITIONS

Pin #	Name	Description
1	GND	Ground. The SenseFET source terminal on primary side and the internal PWM control ground.
2	V <sub>CC</sub>	Power Supply Voltage Input. This pin is the positive supply input, which provides the internal operating current for startup and steady-state operation. This voltage is supplied from internal high-voltage regulator via pin 5 (V <sub>STR</sub> ) during startup (see Figure 2). When the external bias voltage is higher than 10 V, internal high voltage regulator is disable. A ceramic capacitor need to be placed as close as possible between this pin and pin 1 (GND). Recommended distance is less than 3 mm.
3	FB	Feedback. This pin is internally connected to the inverting input to the PWM comparator. This pin has a 100 $\mu$ A current source internally. The collector of an opto-coupler is typically tied to this pin. A capacitor should be placed between this pin and GND. A resistor should be connected between this pin and pin 2 (V <sub>CC</sub> ) to generate delay current (I <sub>DELAY</sub> ) for overload protection delay time. The resistance should not be exceed 5 M $\Omega$ in self-biasing.
4	V <sub>IN</sub>	Line Over-Voltage Input. This pin is the input of divided line voltage. The voltage is divided by resistors. When this voltage is higher than 2 V, the FSL4110LR is not operationed. If this pin is not used, it should be connected to the ground.
5	V <sub>STR</sub>	Startup. Connected to the rectified AC line voltage source. At startup, the internal switch supplies internal bias and charges an external storage capacitor placed between V <sub>CC</sub> pin and ground. Once V <sub>CC</sub> reaches 12 V, all internal blocks are activated. The internal high-voltage regulator turns on and off to maintain V <sub>CC</sub> at 10 V without auxiliary bias winding.
6, 7	Drain	Drain. Designed to connect directly to the primary lead of the transformer and capable of switching a maximum of 1000 V. Minimizing the length of the trace connecting these pins to the transformer decreases leakage inductance.

# FSL4110LR

## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Min	Max	Unit	
$V_{STR}$	$V_{STR}$ Pin Voltage	–	700	V	
$V_{DS}$	Drain Pin Voltage	–	1000	V	
$V_{CC}$	$V_{CC}$ Pin Voltage	–	27	V	
$V_{FB}$	Feedback Pin Voltage (Note 3)	–0.3	12.0	V	
$V_{IN}$	$V_{IN}$ Pin Voltage (Note 3)	–0.3	12.0	V	
$I_{DM}$	Drain Current Pulsed	–	4	A	
$I_{DS}$	Continuous Switching Drain Current (Note 4)	$T_C = 25^\circ\text{C}$	–	1	A
		$T_C = 100^\circ\text{C}$	–	0.6	A
$E_{AS}$	Single Pulsed Avalanche Energy (Note 5)	–	51	mJ	
$P_D$	Total Power Dissipation ( $T_C = 25^\circ\text{C}$ ) (Note 6)	–	1.5	W	
$T_J$	Maximum Junction Temperature	–	150	$^\circ\text{C}$	
	Operating Junction Temperature (Note 7)	–40	+125	$^\circ\text{C}$	
TSTG	Storage Temperature	–55	+150	$^\circ\text{C}$	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- $V_{FB}$  and  $V_{IN}$  are clamped by internal clamping diode (11 V,  $I_{CLAMP\_MAX} < 100 \mu\text{A}$ ).
- Repetitive peak switching current when the inductive load is assumed: Limited by maximum duty ( $D_{MAX} = 0.73$ ) and junction temperature (see Figure 4).
- $I_{AS} = 3.2 \text{ A}$ ,  $L = 10 \text{ mH}$ , starting  $T_J = 25^\circ\text{C}$ .
- Infinite cooling condition (refer to the SEMI G30–88).
- Although this parameter guarantees IC operation, it does not guarantee all electrical characteristics.

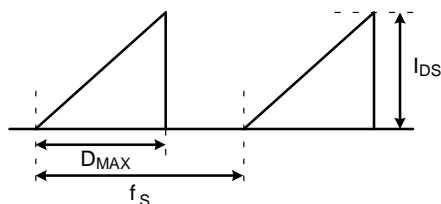


Figure 4. Repetitive Peak Switching Current

## THERMAL IMPEDANCE

Symbol	Parameter	Value	Unit
$\theta_{JA}$	Junction-to-Ambient Thermal Impedance (Note 8)	85	$^\circ\text{C/W}$

- JEDEC recommended environment, JESD51–2, and test board, JESD51–3, with minimum land pattern.

## ESD CAPABILITY

Symbol	Parameter	Value	Unit
ESD	Human Body Model, ANSI/ESDA/JEDEC JS–001–2012	5.0	KV
	Charged Device Model, JESD22–C101	2.0	

# FSL4110LR

## ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = -40°C to 125°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
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### SenseFET SECTION

BV <sub>DSS</sub>	Drain–Source Breakdown Voltage (Note 9)	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA	1000	–	–	V
I <sub>DSS</sub>	Zero–Gate–Voltage Drain Current (Note 9)	V <sub>DS</sub> = 1000 V, V <sub>GS</sub> = 0 V	–	–	250	μA
R <sub>DS(ON)</sub>	Drain–Source On–State Resistance (Note 9)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 1.0 A	–	–	10	Ω
C <sub>ISS</sub>	Input Capacitance (Note 9) (Note 10)	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	–	367	477	pF
C <sub>OSS</sub>	Output Capacitance (Note 9) (Note 10)		–	37.5	48.8	pF
t <sub>d(on)</sub>	Turn–On Delay Time (Note 9)	V <sub>DD</sub> = 500 V, I <sub>D</sub> = 1.0 A, V <sub>GS</sub> = 10 V, R <sub>g</sub> = 25 Ω	–	13.7	–	ns
t <sub>r</sub>	Rise Time (Note 9)		–	14	–	ns
t <sub>d(off)</sub>	Turn–Off Delay Time (Note 9)		–	33	–	ns
t <sub>f</sub>	Fall Time (Note 9)		–	45	–	ns

### CONTROL SECTION

f <sub>S</sub>	Switching Frequency (Note 9)	V <sub>CC</sub> = 14 V, V <sub>FB</sub> = 4 V	46.5	50.0	53.5	kHz
f <sub>M</sub>	Frequency Modulation (Note 10)		–	±1.5	–	kHz
D <sub>MAX</sub>	Maximum Duty Ratio	V <sub>CC</sub> = 14 V, V <sub>FB</sub> = 4 V	61	67	73	%
I <sub>FB</sub>	Feedback Source Current (Note 9)	V <sub>FB</sub> = 0 V	70	100	130	μA
V <sub>START</sub>	UVLO Threshold Voltage	V <sub>FB</sub> = 0 V, V <sub>CC</sub> Sweep	11	12	13	V
V <sub>STOP</sub>		After Turn–on, V <sub>FB</sub> = 0 V	7	8	9	
t <sub>S/S</sub>	Internal Soft–Start Time	V <sub>STR</sub> = 40 V, V <sub>CC</sub> Sweep	–	20	–	ms

### BURST–MODE SECTION

V <sub>BURH</sub>	Burst–Mode Voltage (Note 9)	V <sub>CC</sub> = 14 V, V <sub>FB</sub> Sweep	0.45	0.50	0.55	V
V <sub>BURL</sub>			0.35	0.40	0.45	V
V <sub>HYS</sub>			–	100	–	mV

### PROTECTION SECTION

I <sub>LIM</sub>	Peak Drain Current Limit (Note 9)	di/dt = 240 mA/μs	0.45	0.52	0.59	A
V <sub>OLP</sub>	Overload Protection (Note 9)	V <sub>CC</sub> = 14 V, V <sub>FB</sub> Sweep	4.0	4.4	4.8	V
V <sub>AOCP</sub>	Abnormal Over–Current Protection (Note 10)		–	1.0	–	V
t <sub>LEB</sub>	Leading–Edge Blanking Time (Note 10) (Note 11)		–	250	–	ns
t <sub>CLD</sub>	Current Limit Delay Time (Note 10)		–	–	200	ns
V <sub>OVP</sub>	Over–Voltage Protection	V <sub>CC</sub> Sweep	23.0	24.5	26.0	V
V <sub>INH</sub>	Line Over–Voltage Protection Threshold Voltage	V <sub>CC</sub> = 14 V, V <sub>IN</sub> Sweep	1.9	2.0	2.1	V
V <sub>INHYS</sub>	Line Over–Voltage Protection Hysteresis (Note 9)	V <sub>CC</sub> = 14 V, V <sub>IN</sub> Sweep	–	100	–	mV
t <sub>DELAY</sub>	Overload Protection Delay		–	100	–	ms
t <sub>RESTART</sub>	Restart Time After Protection (Note 10)		–	1.6	–	s
TSD	Thermal Shutdown Temperature (Note 10)	Shutdown Temperature	130	140	150	°C
T <sub>HYS</sub>		Hysteresis (FSL4110LRN)	–	60	–	
T <sub>HYS</sub>		Hysteresis (FSL4110LRLX)	–	30	–	

### HIGH VOLTAGE REGULATOR SECTION

V <sub>HVREG</sub>	HV Regulator Voltage	V <sub>FB</sub> = 0 V, V <sub>STR</sub> = 40 V	9	10	11	V
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# FSL4110LR

## ELECTRICAL CHARACTERISTICS ( $T_J = -40^{\circ}\text{C}$ to $125^{\circ}\text{C}$ unless otherwise noted) (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>TOTAL DEVICE SECTION</b>						
$I_{OP}$	Operating Supply Current, (Control Part in Burst Mode) (Note 9)	$V_{CC} = 14\text{ V}$ , $V_{FB} = 0\text{ V}$	–	0.40	0.50	mA
$I_{OPS}$	Operating Switching Current, (Control Part and SenseFET Part) (Note 9)	$V_{CC} = 14\text{ V}$ , $V_{FB} = 2\text{ V}$	–	1.00	1.35	mA
$I_{START}$	Start Current (Note 9)	$V_{CC} = 11\text{ V}$ (Before $V_{CC}$ Reaches $V_{START}$ )	–	160	240	$\mu\text{A}$
$I_{CH}$	Startup Charging Current (Note 9)	$V_{CC} = V_{FB} = 0\text{ V}$ , $V_{STR} = 40\text{ V}$	1.5	2.0	–	mA
$V_{STR}$	Minimum $V_{STR}$ Supply Voltage	$C_{VCC} = 0.1\ \mu\text{F}$ , $V_{STR}$ Sweep	–	–	26	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

9.  $T_J = 25^{\circ}\text{C}$ .

10. Although these parameters are guaranteed, they are not 100% tested in production.

11.  $t_{LEB}$  includes gate turn-on time.

# FSL4110LR

## TYPICAL PERFORMANCE CHARACTERISTICS

(Characteristic graphs are normalized at  $T_A = 25^\circ\text{C}$ .)

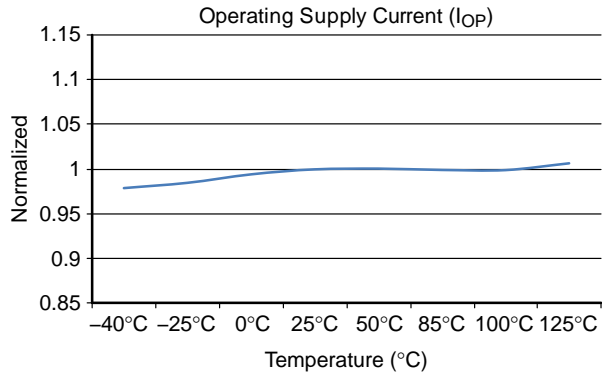


Figure 5. Operating Supply Current ( $I_{OP}$ ) vs.  $T_A$

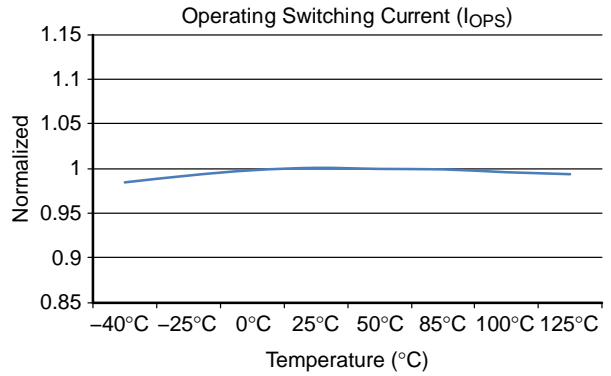


Figure 6. Operating Switching Current ( $I_{OPS}$ ) vs.  $T_A$

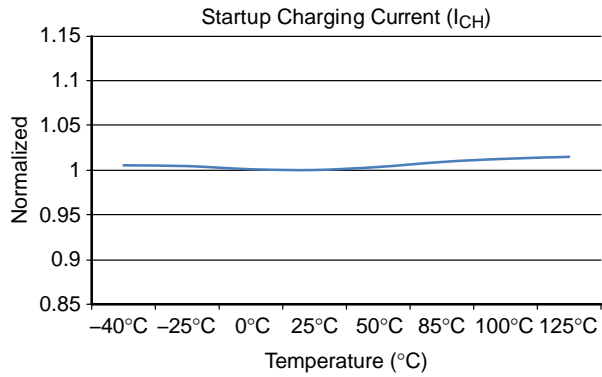


Figure 7. Startup Charging Current ( $I_{CH}$ ) vs.  $T_A$

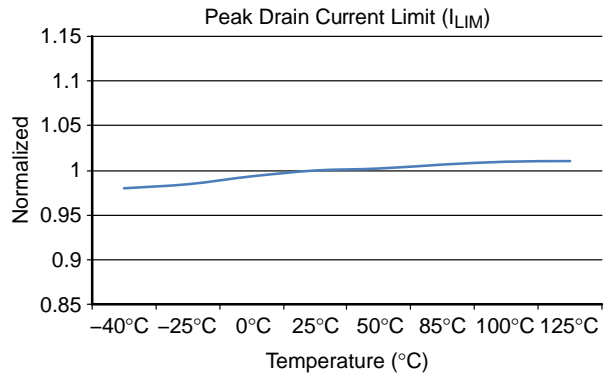


Figure 8. Peak Drain Current Limit ( $I_{LIM}$ ) vs.  $T_A$

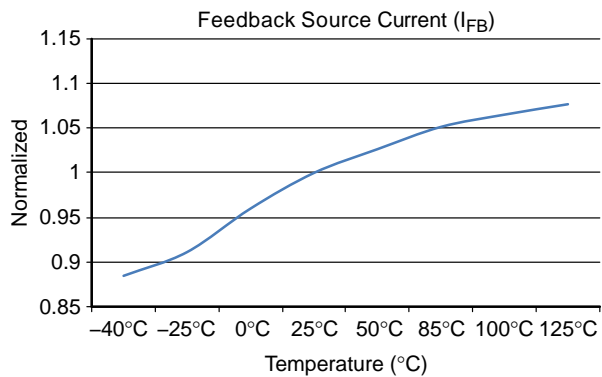


Figure 9. Feedback Source Current ( $I_{FB}$ ) vs.  $T_A$

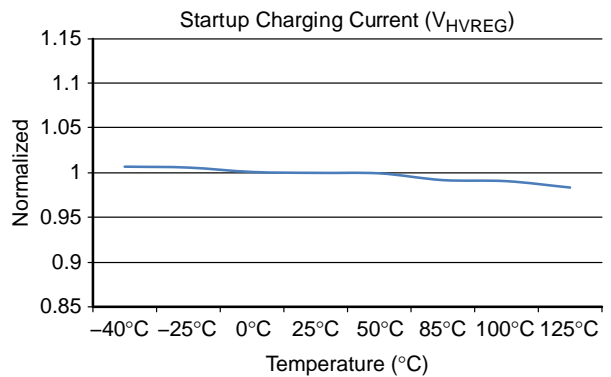


Figure 10. HV Regulator Voltage ( $V_{HVREG}$ ) vs.  $T_A$

# FSL4110LR

## TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(Characteristic graphs are normalized at  $T_A = 25^\circ\text{C}$ .)

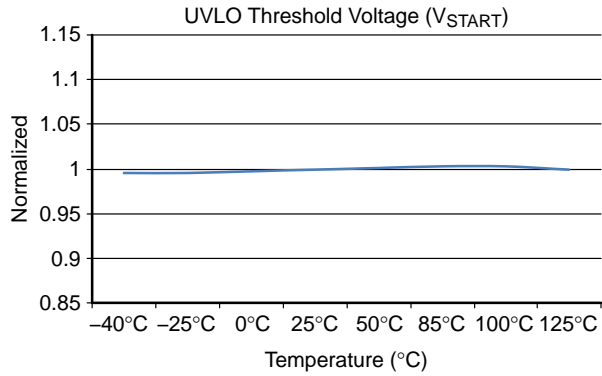


Figure 11. UVLO Threshold Voltage ( $V_{START}$ ) vs.  $T_A$

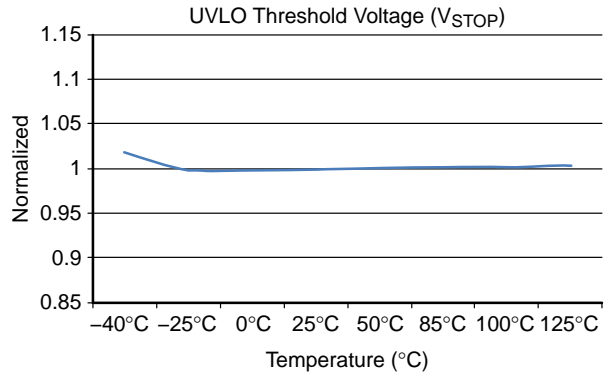


Figure 12. UVLO Threshold Voltage ( $V_{STOP}$ ) vs.  $T_A$

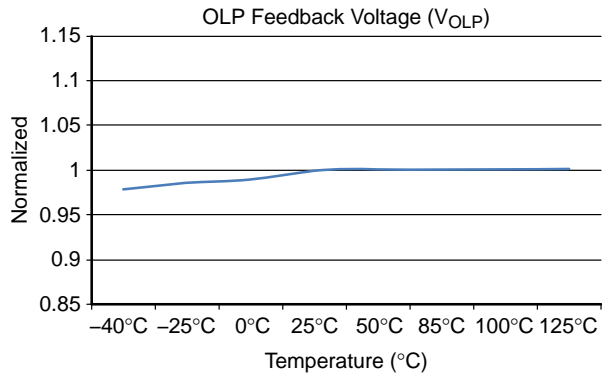


Figure 13. OLP Feedback Voltage ( $V_{OLP}$ ) vs.  $T_A$

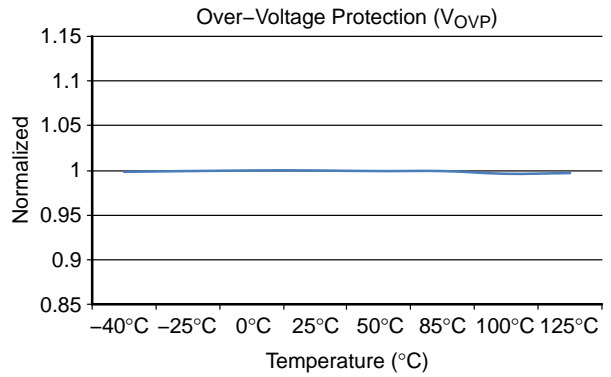


Figure 14. Over-Voltage Protection ( $V_{OVP}$ ) vs.  $T_A$

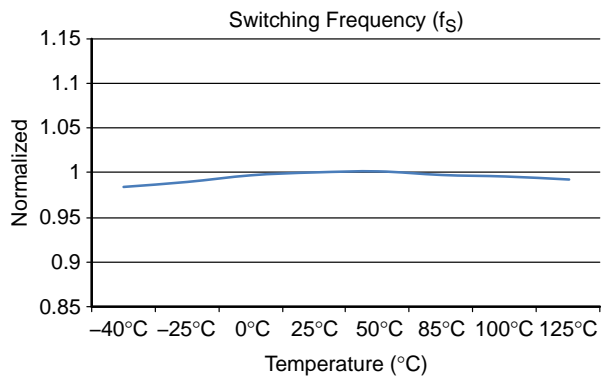


Figure 15. Switching Frequency ( $f_s$ ) vs.  $T_A$

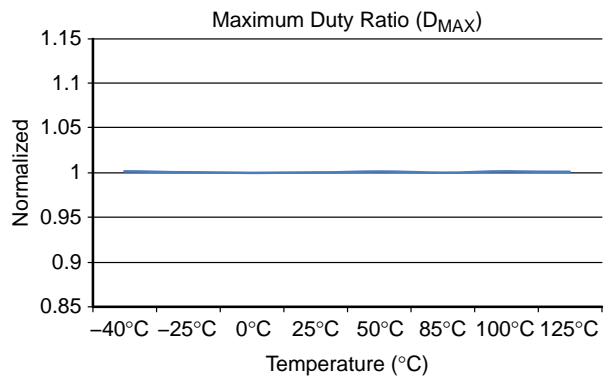


Figure 16. Maximum Duty Ratio ( $D_{MAX}$ ) vs.  $T_A$





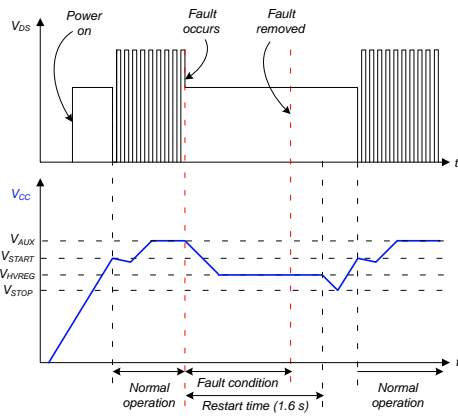


Figure 19. Auto-Restart Protection Waveforms

Overload Protection (OLP)

Overload is defined as the load current exceeding its normal level due to an unexpected abnormal event. In this situation, the protection circuit should trigger to protect the SMPS. However, even when the SMPS is in normal operation, the overload protection circuit can be triggered during load transition. To avoid this undesired operation, the overload protection circuit is designed to trigger only after a specified time to determine whether it is a transient situation or a true overload situation. Because of the pulse-by-pulse current-limit capability, the maximum peak current through the SenseFET is limited. If the output consumes more than this maximum power, the output voltage decreases below the set voltage. This reduces the current through the opto-diode, which also reduces the opto-coupler transistor current, thus increasing the feedback voltage ( $V_{FB}$ ). If  $V_{FB}$  exceeds 2.4 V, internal diode D1 is blocked and the current ( $I_{DLY}$ ) by  $R_{DLY}$  starts to charge  $C_{FB}$ . If feedback voltage reaches 4.4 V, internal fixed delay time ( $t_{DELAY}$ ) starts counting. If feedback voltage maintains over 4.4 V after  $t_{DELAY}$  (100 ms), the switching operation is terminated (see Figure 20). The internal OLP circuit is shown in Figure 21.

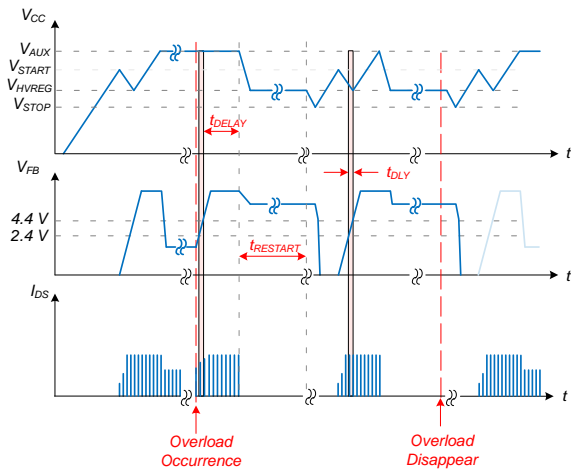


Figure 20. OLP Waveforms

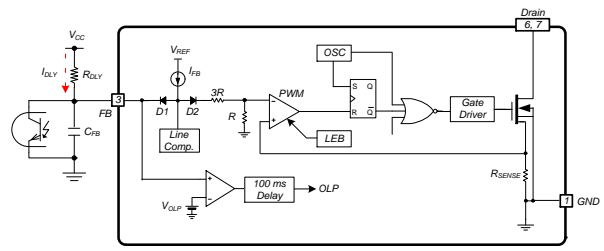


Figure 21. OLP Circuit

Recommended the  $R_{DLY}$  value is less than 5 MΩ in self-biasing. The delay time ( $t_{DLY}$ ) can be calculated by equation (3).

$$t_{DLY} = -R_{DLY} \times C_{FB} \times \ln\left(1 - \frac{2}{V_{CC} - 2.4}\right) \quad (\text{eq. 3})$$

Example:

When,  $R_{DLY} = 3 \text{ M}\Omega$ ,  $C_{FB} = 68 \text{ nF}$ ,  $V_{CC} = 15 \text{ V}$ ,  
 $t_{DLY} = 35 \text{ ms}$

∴ Total delay time for OLP: 135 ms

Abnormal Over-Current Protection (AOCP)

When the secondary rectifier diodes or the transformer pins are shorted, a steep current with extremely high di/dt can flow through the SenseFET during the minimum turn-on time. Overload protection is not enough to protect the FSL4110LR in that abnormal case (see Figure 22); since severe current stress is imposed on the SenseFET until OLP is triggered. The internal AOCP circuit is shown in Figure 23. When the gate turn-on signal is applied to the power SenseFET, the AOCP block is enabled and monitors the current through the sensing-resistor. The voltage across the resistor is compared with a preset AOCP level. If the sensing resistor voltage is greater than the AOCP level, the high signal is applied to input of the NOR gate, resulting in the shutdown of the SMPS.

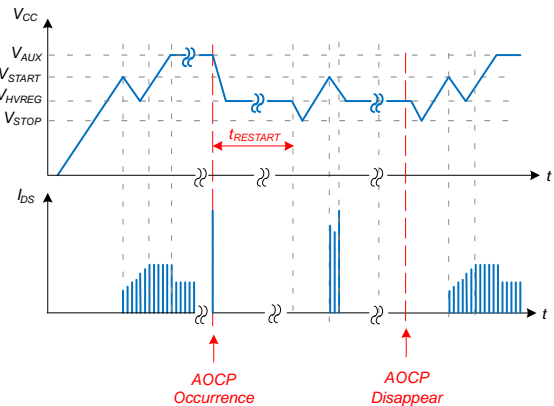


Figure 22. AOCP Waveforms

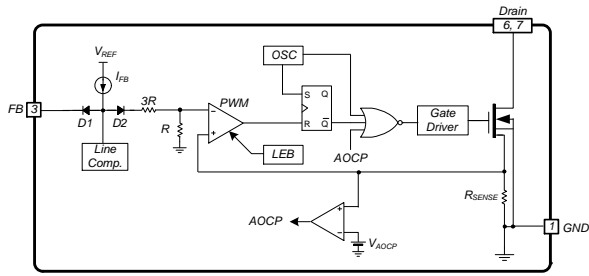


Figure 23. AOCPS Circuit

Over-Voltage Protection (OVP)

If the secondary-side feedback circuit malfunctions or a solder defect causes an opening in the feedback path, the current through the opto-coupler transistor becomes almost zero. Then  $V_{FB}$  climbs in a similar manner to the overload situation, forcing the preset maximum drain current to flow until the overload protection is triggered. Because more energy than required is provided to the output, the output voltage may exceed the rated voltage before the overload protection is triggered, resulting in the breakdown of the devices in the secondary side. To prevent this situation, an OVP circuit is employed. In general, the  $V_{CC}$  is proportional to the output voltage when the bias-winding is used and the FSL4110LR uses  $V_{CC}$  instead of directly monitoring the output voltage. If  $V_{CC}$  exceeds 24.5 V, an OVP circuit is triggered, resulting in the termination of the switching operation. To avoid undesired activation of OVP during normal operation,  $V_{CC}$  should be designed to be below 24.5 V in the normal conditions. The internal OVP circuit is shown in Figure 24.

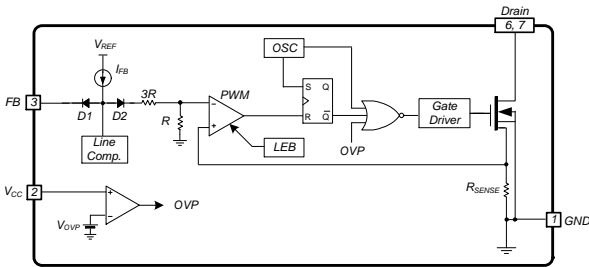


Figure 24. OVP Circuit

Thermal Shutdown (TSD)

The SenseFET and control IC integrated on the same package makes it easier to detect the temperature of the SenseFET. When the junction temperature exceeds 140°C, thermal shutdown is activated. The FSL4110LR is restarted when the temperature decreases by 60°C within  $t_{RESTART}$  (1.6 s).

Line Over-Voltage Protection (LOVP)

If the line input voltage is increased to an undesirable level, high line input voltage creates high-voltage stress on the entire system. To protect the SMPS from this abnormal condition, LOVP is included. It is comprised of detecting  $V_{IN}$  voltage by using divided resistors. When voltage of  $V_{IN}$  voltage is higher than 2.0 V, this condition is recognized as an

abnormal error and PWM switching shuts down until voltage of  $V_{IN}$  voltage decreases to around 1.9 V within  $t_{RESTART}$  (see Figure 25). The internal LOVP circuit is shown in Figure 26.

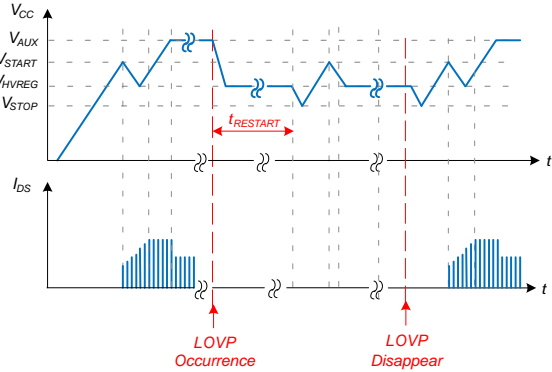


Figure 25. LOVP Waveforms

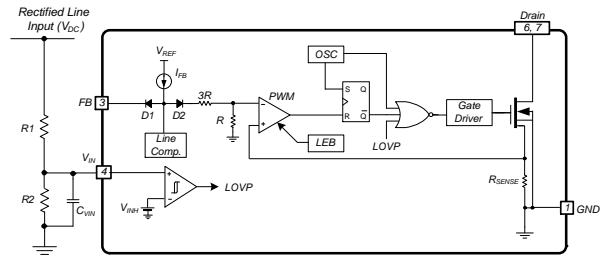


Figure 26. LOVP Circuit

Equation (4) calculates the level of input over-voltage to RMS value.

$$R2 = \frac{V_{INH} \times R1}{V_{DC} - V_{INH}} \quad (\text{eq. 4})$$

The resistance of divided resistor can be adjusted as necessary. Small resistance can bring relatively large stand-by power consumption at light-load condition. To avoid this situation, a several MΩ resistor is recommended. For stable operation, a several MΩ resistor should accompany a capacitor ( $C_{VIN}$ ) with hundreds of pF capacitance between the  $V_{IN}$  pin and GND.

Oscillator Block

The oscillator frequency is set internally and the FSL4110LR has a random frequency fluctuation function as shown in Figure 27. Fluctuation of the switching frequency can reduce EMI by spreading the energy over a wider frequency range than the bandwidth measured by the EMI test equipment. The range of frequency variation is fixed internally; however, its selection is randomly chosen by the combination of an external feedback voltage and an internal free-running oscillator. This randomly chosen switching frequency effectively spreads the EMI noise near switching frequency and allows the use of a cost-effective inductor instead of an AC input line filter to satisfy world-wide EMI requirements.

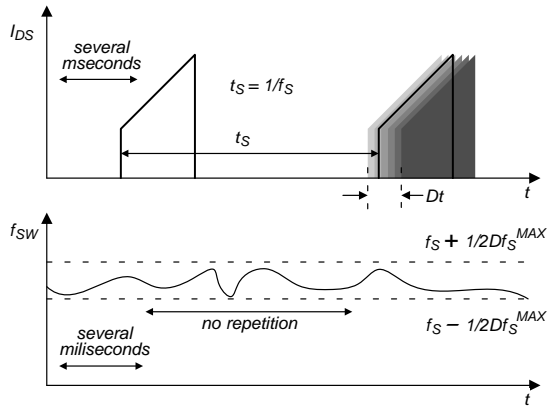


Figure 27. Frequency Fluctuation Waveforms

**Soft-Start**

The internal soft-start circuit slowly increases the SenseFET current after it starts. The typical soft-start time is 20 ms, as shown in Figure 28, where progressive increments of the SenseFET current are allowed during startup. The pulse width to the power switching device is progressively increased to establish the correct working conditions for transformers, inductors, and capacitors. The voltage on the output capacitors is gradually increased to smoothly establish the required output voltage. Soft-start also helps to prevent transformer saturation and reduces stress on the secondary diode.

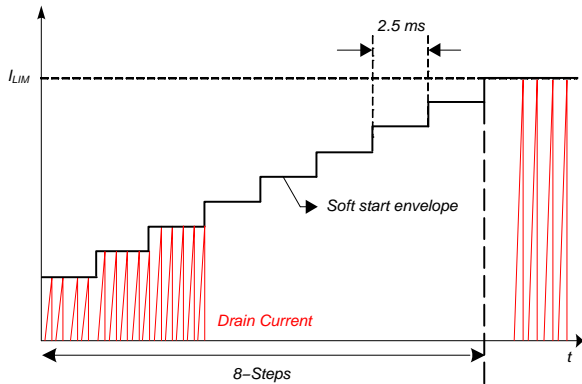


Figure 28. Internal Soft-Start

**Burst Mode Operation**

To minimize power dissipation in standby mode, the FSL4110LR enters burst mode. As the load decreases, the feedback voltage decreases. The device automatically enters burst mode when the feedback voltage drops below  $V_{BURL}$  (400 mV), as shown in Figure 29. At this point, switching stops and the output voltages start to drop at a rate dependent on standby current load. This causes the feedback voltage to rise. Once it passes  $V_{BURH}$  (500 mV), switching resumes. Feedback voltage then falls and the process repeats. Burst Mode alternately enables and disables switching of the SenseFET, reducing switching loss in standby mode.

Additionally to reduce the audible noise soft-burst is implemented.

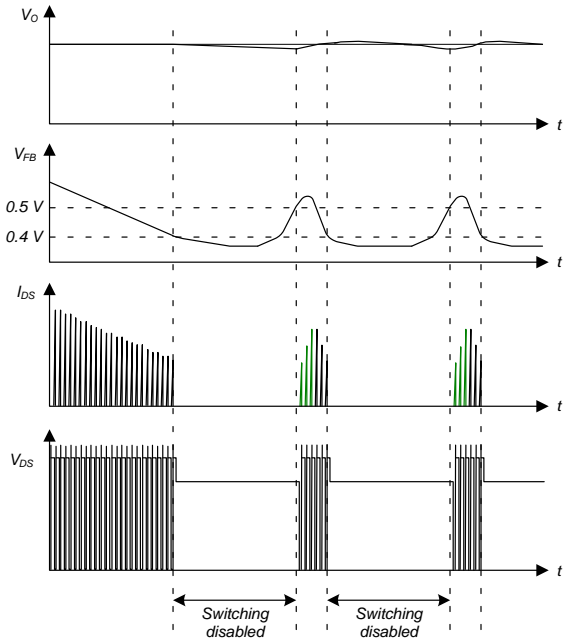


Figure 29. Burst Mode Operation

**Line Compensation**

All of switching devices have their own inherent propagation delays. This propagation delay will cause a current limit delay defined as  $t_{CLD}$ . Because there is a current limit delay,  $t_{CLD}$ , there is a difference in the current peak between low and high input voltage. The variance in the current peak is related to the difference between the input voltages, a wider gap in input voltage will result in a greater variance of the current peak.

In order to have a constant current peak regardless of the input voltage, line compensation is required. FSL4110LR has line compensation, so the real peak value of high input voltage is similar to that of low input voltage.  $t_{CLD}$  effect could be neglected as showed Figure 30.

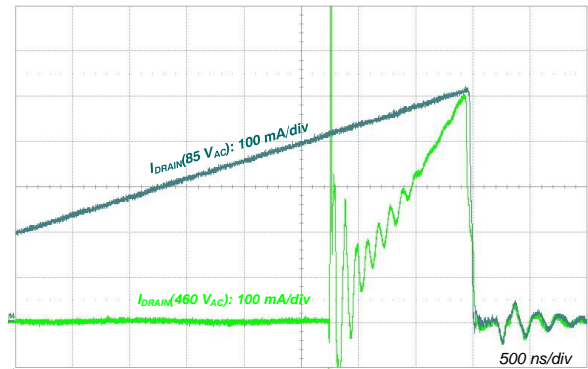


Figure 30.  $I_{LIMIT}$  Waveforms (85  $V_{AC}$  vs. 460  $V_{AC}$ )

# FSL4110LR

## ORDERING INFORMATION

Part Number	Package	Operating Junction Temperature	Current Limit	R <sub>DS(ON)</sub> (Max)	Output Power Table (Note 12)		Shipping†
					45~460 V <sub>AC</sub> (Note 13)	85~460 V <sub>AC</sub> (Note 13)	
FSL4110LRN	PDIP-7 (PDIP-8 LESS PIN 6) (7-DIP) (Pb-Free)	-40°C~125°C	0.52 A	10 Ω	4 W (Note 14)	9 W (Note 14)	3000 Units / Tube
FSL4110LRLX	PDIP7 MINUS PIN 6 GW (7-LSOP) (Pb-Free)						1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

12. The junction temperature can limit the maximum output power.

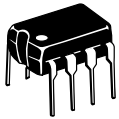
13. Maximum practical continuous power in an open-frame design at 50°C ambient temperatures.

14. Bias winding condition.

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

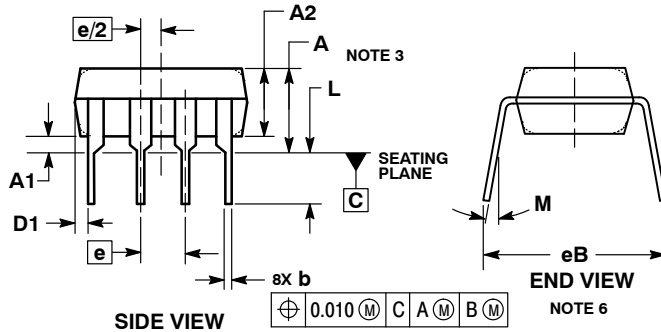
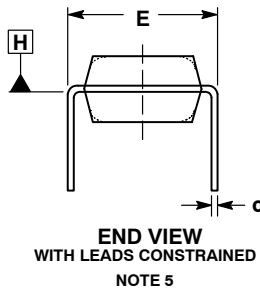
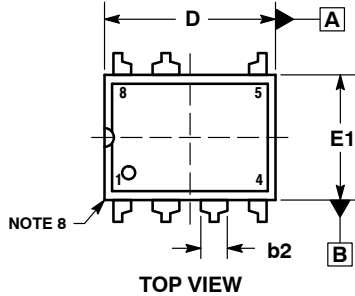
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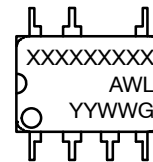


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH.
5. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
6. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.
7. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.
8. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	----	0.210	----	5.33
A1	0.015	----	0.38	----
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060 TYP		1.52 TYP	
C	0.008	0.014	0.20	0.36
D	0.355	0.400	9.02	10.16
D1	0.005	----	0.13	----
E	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
e	0.100 BSC		2.54 BSC	
eB	----	0.430	----	10.92
L	0.115	0.150	2.92	3.81
M	----	10°	----	10°

### GENERIC MARKING DIAGRAM\*



- XXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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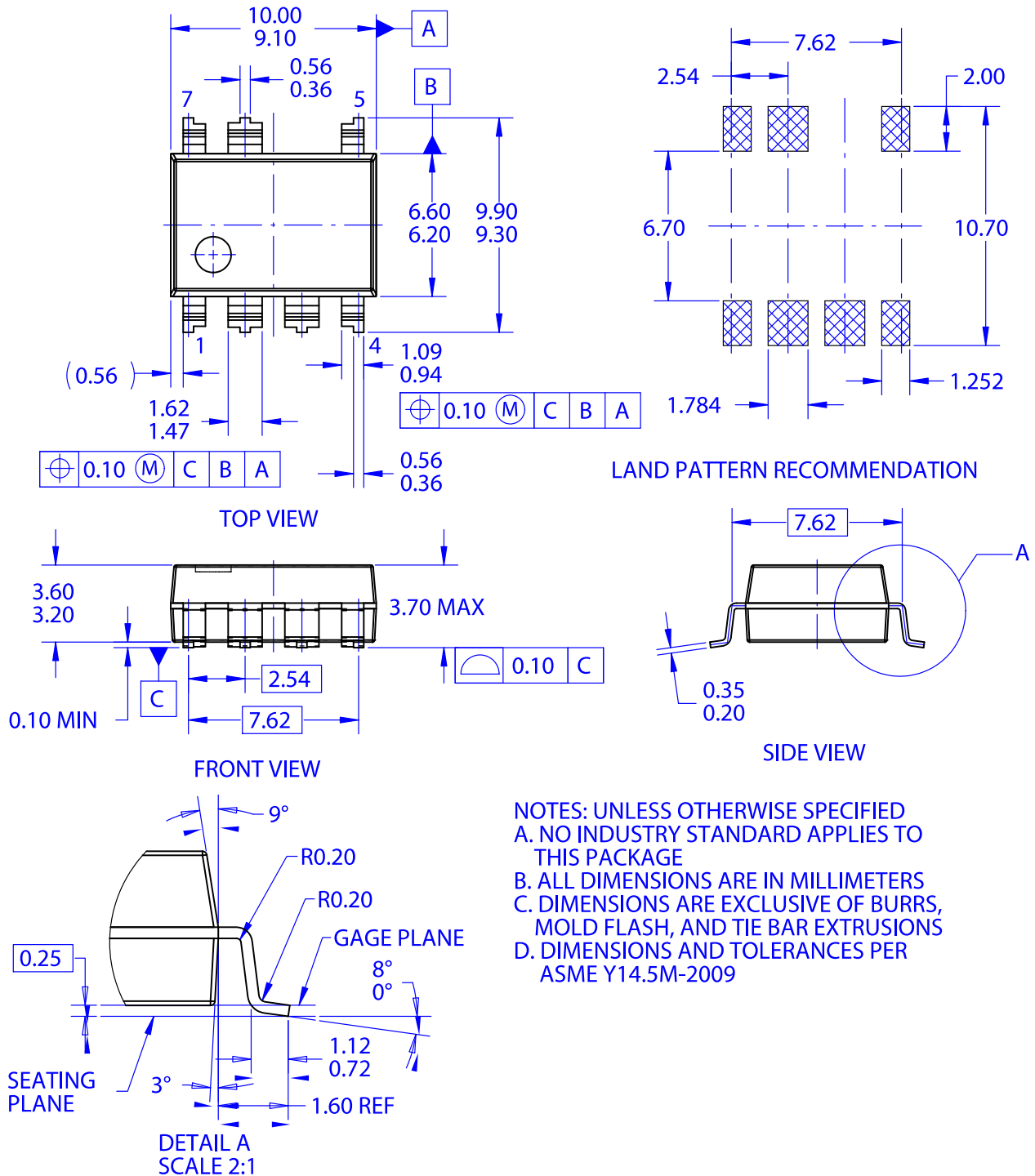
**MECHANICAL CASE OUTLINE**  
**PACKAGE DIMENSIONS**

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**CASE 707AA**  
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